Unitized Semiconductor Devices - Page 1 of 1



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| Inclosure Material: |
|---|
| Plastic |
| Overall Length: |
| 0.500 inches |
| Overall Height: |
| 0.250 inches |
| Overall Width: |
| 0.468 inches |
| Component Name And Quantity: |
| 4 semiconductor device diode |
| Mounting Method: |
| Terminal |
| Semiconductor Material: |
| Silicon all semiconductor device diode |
| Voltage Rating In Volts Per Characteristic: |
| 50.0 working peak reverse voltage, peak total value all semiconductor device diode |
| Current Rating Per Characteristic: |
| 100.00 milliamperes forward current, average minor all semiconductor device diode |
| Power Rating Per Characteristic: |
| 250.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode |
| Maximum Operating Tempurature Per Measurement Point: |
| 100.0 degrees celsius ambient air |
| Special Features: |
| All semiconductor device diode junction pattern arrangement: pn |
| Terminal Type And Quantity: |
| 8 uninsulated wire lead |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
| |